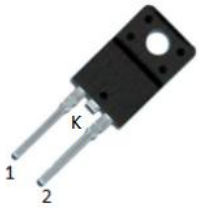
Technical Data
Data Sheet N3077, REV.-

S3D03065F
3A 650V SIC POWER SCHOTTKY RECTIFIERS



ITO-220AC(TO-220-F2)

Description

This 650V 3A diode is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D03065F is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram

Features

- 175°C TJ operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

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Maximum Ratings@T_A=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	-	650	V
Average Rectified Forward Current	$I_{F(AV)1}$	Tc=25°C	9	A
	$I_{F(AV)2}$	Tc=135°C	4	A
	$I_{F(AV)3}$	Tc=150°C	3	A
Repetitive Peak Forward Surge Current	I_{FRM1}	10ms, Half Sine pulse, Tc=25°C	16	A
	I_{FRM2}	10ms, Half Sine pulse, Tc=110°C	14	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM1}	10ms, Half Sine pulse, Tc=25°C	27	A
	I_{FSM2}	10ms, Half Sine pulse, Tc=110°C	25	A
Non-Repetitive Peak Forward Surge Current	$I_{F,Max1}$	10μs. Pulse, Tc=25°C	390	A
	$I_{F,Max2}$	10μs. Pulse, Tc=110°C	265	A
Power Dissipation	P_{tot1}	Tc=25°C	31	W
	P_{tot2}	Tc=110°C	13	W

Electrical Characteristics@T_A=25°C unless otherwise specified

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 3A, Pulse, T_J = 25 °C	1.4	1.7	V
	V_{F2}	@ 3A, Pulse, T_J = 175 °C	1.6	2.0	V
Reverse Current*	I_{R1}	@V_R = rated V_R T_J = 25 °C	0.03	2	uA
	I_{R2}	@V_R = rated V_R T_J = 175 °C	0.3	20	uA
Junction Capacitance	C_T	V_R=0V, T_J=25°C, f=1MHz	230	-	pF
Reverse Recovery Charge	Q_c	I_F = 3A, di/dt = 200A/μs VR = 400 V, T_J =25°C	14.35	-	nC
Capacitance Stored Energy	EC	VR = 400 V, T_J =25°C	3.51	-	μJ

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications@T_A=25˚C unless otherwise specified

Characteristics	Symbol	S3D03065F	Units
Junction Temperature	T_J	-55 to +175	˚C
Storage Temperature	T_{stg}	-55 to +175	˚C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	4.85	˚C/W

Ordering Information

Device	Package	Shipping
S3D03065F	ITO-220AC(TO-220-F2)	50pcs / tube
S3D03065F-A	ITO-220AC(TO-220-F2)	50pcs / tube

Ratings and Characteristics Curves

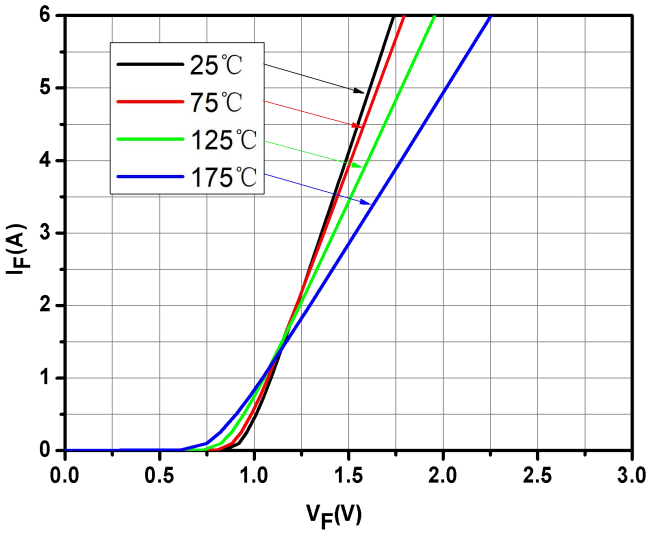

Fig.1-Typical Forward Voltage Characteristics

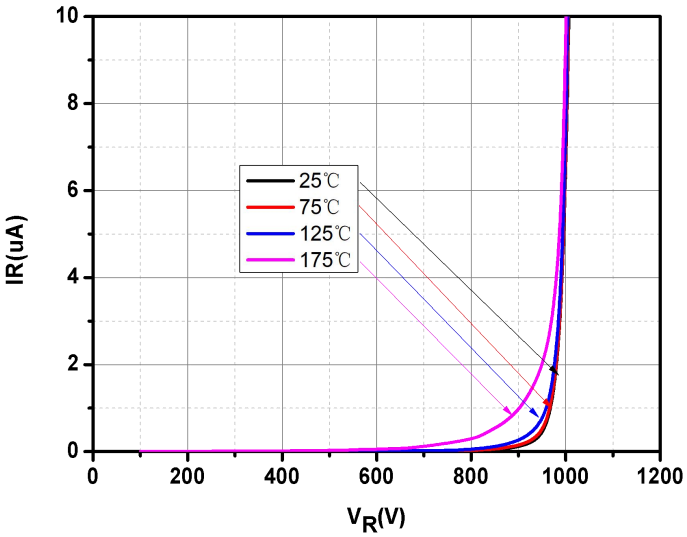

Fig.2-Typical Reverse Characteristics

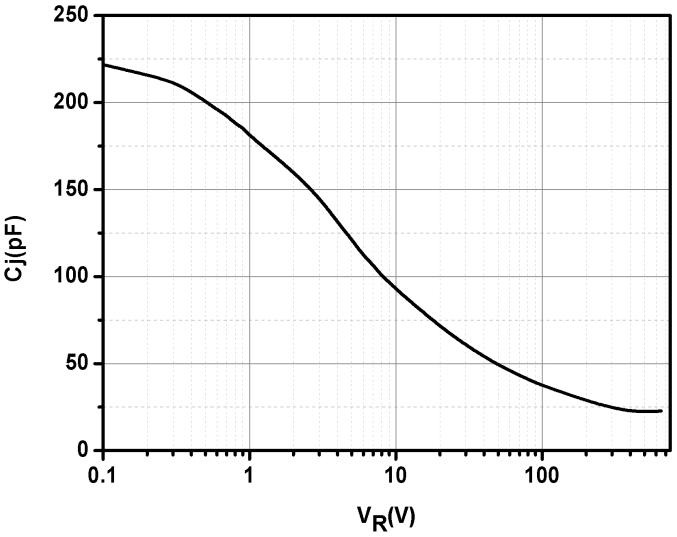

Fig.3-Capacitance vs. Reverse Voltage

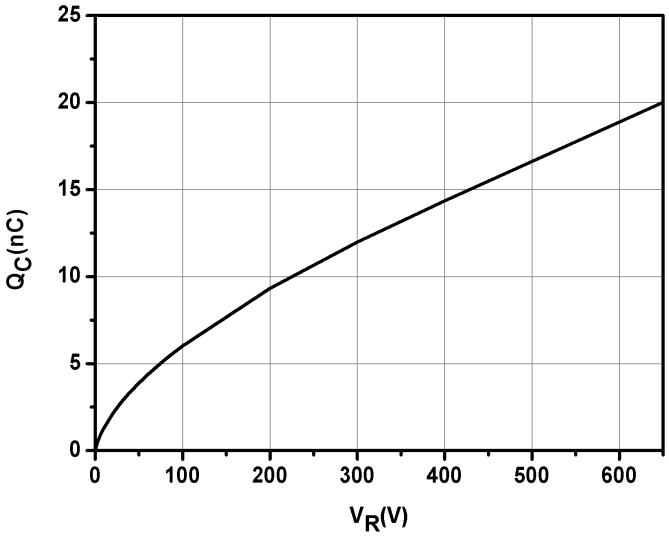

Fig.4-Total Capacitance Charge vs. Reverse Voltage

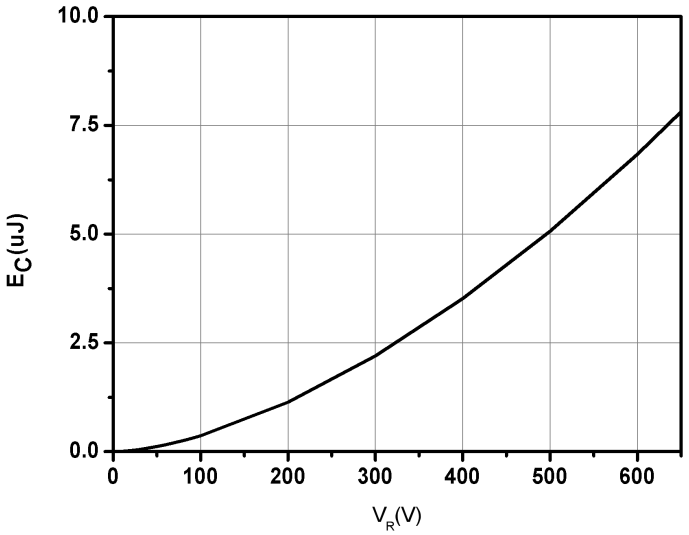

Fig.5-Capacitance Stored Energy

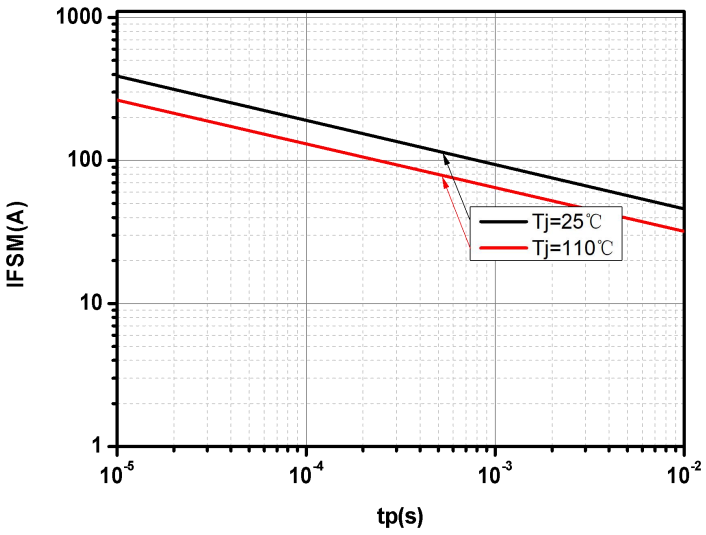

Fig.6-Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

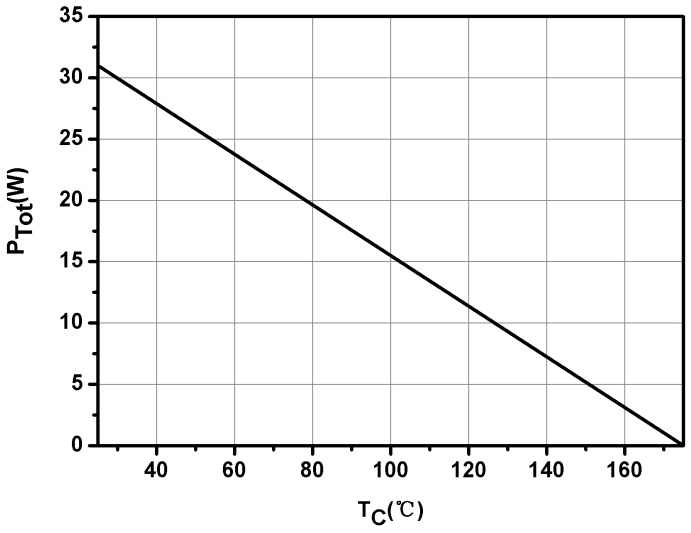

Fig.7-Power Derating

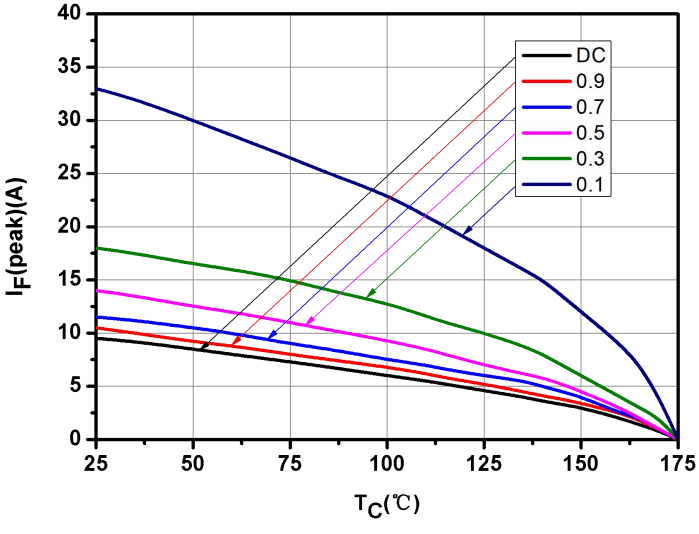

Fig.8-Current Derating

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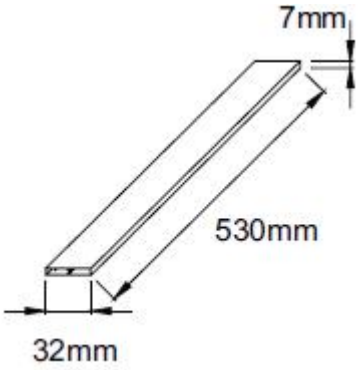
Marking Diagram

Where XXXXX is YYWWL

S3D	= Device Type
F	= Package type
03	= Forward Current (3A)
065	= Reverse Voltage (650V)
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Tube Specification(TO-220-Isolation)



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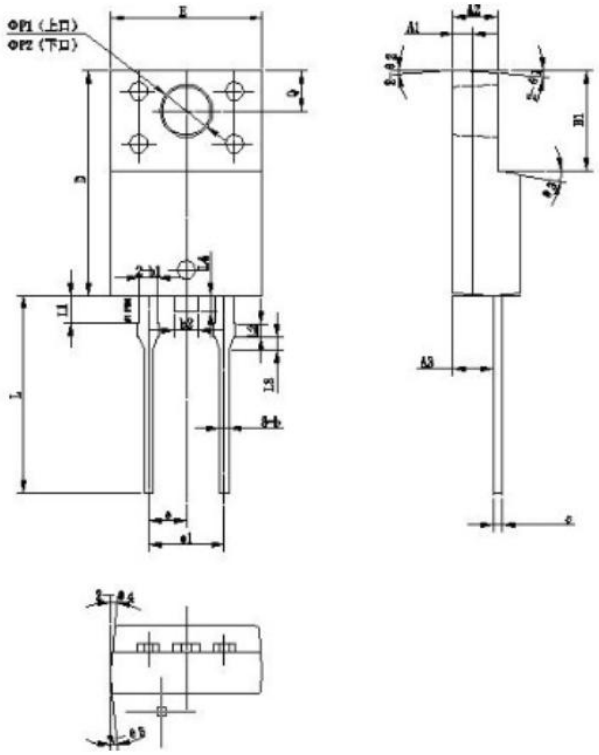
Mechanical Dimensions ITO-220AC(TO-220-2F)



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.30	4.0	4.70
A1		1.30	
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.5	0.6	0.75
b1		1.20	
b2		1.60	
e	0.55	0.6	0.75
D	14.80	15.00	15.20
E	8.96	10.14	10.36
e		2.55	
e1		5.10	
H1	8.50	8.70	8.90
L	17.70	18.20	18.70
L1		1.80	
L2		1.00	
L3		0.80	
L4		1.10	
ΦP1(上口)	3.30	3.50	3.70
ΦP1(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
θ1		5°	
θ2		4°	
θ3		10°	
θ4		5°	
θ5		5°	

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